# General Purpose Transistor







### Pin Configuration:

- 1. Base
- 2. Collector
- 3. Emitter

### **Description:**

• General Purpose NPN Silicon Planar Epitaxial Amplifier Transistors.

## **Absolute Maximum Ratings**

Parameter	Symbol	Value	Units		
Collector-Emitter Voltage	V <sub>CEO</sub>	50			
Collector-Base Voltage	V <sub>CBO</sub>	V			
Emitter-Base Voltage	V <sub>EBO</sub>	6	1		
Collector Current Continuous	I <sub>C</sub>	100	mA		
Power Dissipation at T <sub>a</sub> = 25°C Derate Above 25°C		350 2.8	mW mW/°C		
Total Device Dissipation at T <sub>c</sub> = 25°C Derate Above 25°C	P <sub>D</sub>	1 8	W mW/°C		
Junction Temperature	T <sub>j</sub>	150	°C		
Storage Temperature	T <sub>stg</sub>	- 55 to + 150			

### **Thermal Resistance**

Junction to Ambient	R <sub>th (j-a)</sub>	375	°C/W
Junction to Case	R <sub>th (j-c)</sub>	125	C/VV

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## Electrical Characteristics ( $T_a = 25$ °C unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Units
Collector-Emitter Voltage	V <sub>CEO</sub>	I <sub>C</sub> = 2mA, I <sub>B</sub> = 0	50	-	-	
Collector-Base Voltage	V <sub>CBO</sub>	$I_{C} = 10\mu A, I_{E} = 0$	60	-	-	V
Emitter-Base Voltage	V <sub>EBO</sub>	I <sub>E</sub> = 100μA, I <sub>C</sub> = 0	6			
Collector Cut off Current	I <sub>CBO</sub>	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	-	-	15	nA
Emitter-Base Leakage Current	I <sub>EB0</sub>	V <sub>EB</sub> = 4.0V, I <sub>C</sub> =0	-	-		
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> = 2mA <b>BC182L</b>	125	-	-	-
Collector-Emitter Saturation Voltage	V <sub>CE (sat)</sub>	$I_{C} = 10 \text{mA}, I_{B} = 0.5 \text{mA}$ * $I_{C} = 100 \text{mA}, I_{B} = 5 \text{mA}$	-	-	0.25 0.6	V
Base-Emitter Saturation Voltage	V <sub>BE (sat)</sub>	*I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA	-	-	1.2	
Base-Emitter On Voltage	V <sub>BE (on)</sub>	$I_C = 100 \mu A, V_{CE} = 5 V$ $I_C = 2 m A, V_{CE} = 5 V$ $*I_C = 100 m A, V_{CE} = 5 V$	0.55	0.5 0.83	0.7	

### **Dynamic Characteristics**

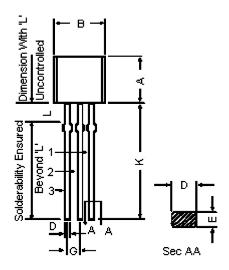
Current-Gain Bandwidth Product	f <sub>T</sub>	$\begin{split} & I_{\rm C} = 0.5 \text{mA, V}_{\rm CE} = 3 \text{V,} \\ & f = 100 \text{MHz} \\ & I_{\rm C} = 10 \text{mA, V}_{\rm CE} = 5 \text{V,} \\ & f = 100 \text{MHz} \end{split}$	150	100	-	MHz
Common Base Output Capacitance	C <sub>ob</sub>	$V_{CB} = 10V, I_{C} = 0,$ f = 1MHz	1	ı	5	pF
Common Base Input Capacitance	Cib	$V_{BE} = 0.5V, I_{C} = 0,$ f = 1MHz	-	8	-	pF
Small-Signal Current Gain	hfe	$I_C = 2mA, V_{CE} = 5V,$ f = 1kHz	125	-	500	-
Noise Figure	NF	$V_{CE} = 5V, I_{C} = 0.2mA,$ $Rs = 2K\Omega,$ f = 1kHz, F = 200Hz	-	-	10	dB

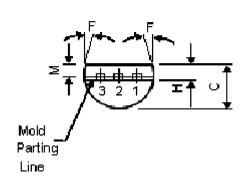
<sup>\*</sup>Pulse Condition : Width ≤300µs, Duty Cycle ≤2%.



# **General Purpose Transistor**







Dimensions	Min.	Max.	
А	4.32	5.33	
В	4.45	5.2	
С	3.18	4.19	
D	0.41	0.55	
E	0.35	0.5	
F	5°		
G	1.14	1.4	
Н	1.2	1.4	
K	12.7	-	
L	1.982	2.082	
М	1.03	1.2	

Dimensions: Millimetres

### **Pin Configuration:**

- 1. Base
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### **Part Number Table**

Description	Part Number		
Transistor, NPN, TO-92	BC182L		

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